





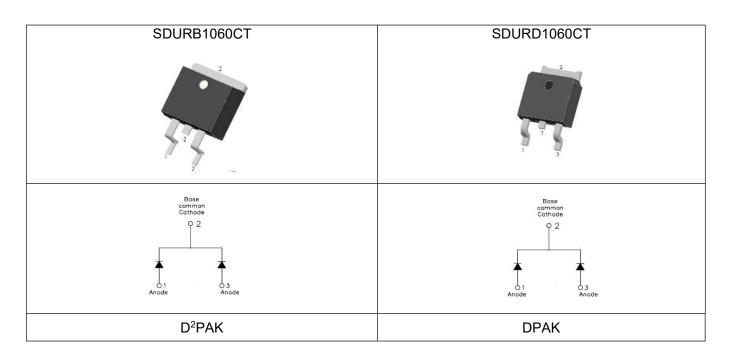
# SDURB1060CT/SDURD1060CT ULTRAFAST RECTIFIER

#### **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

#### **Features**

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	5(Per Leg) 10(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	60	Α

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#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	$V_{F1}$	@ 5A, Pulse, T <sub>J</sub> = 25°C	1.14	1.55	V
	$V_{F2}$	@ 5A, Pulse, T <sub>J</sub> = 125°C	0.95	1.45	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C	0.007	5	μA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_J = 125^{\circ}\text{C}$	3	500	μA
Reverse Recovery Time(Per Leg)	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA	42	50	ns

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	SDURB1060CT SDURD1060CT		Units	
Junction Temperature	TJ	-55 to +150		°C	
Storage Temperature	T <sub>stg</sub>	-55 to +150		°C	
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	2.3	1.7	°C/W	
Case Style	D <sup>2</sup> PAK/ DPAK				

# **Tube Specification**

Device	Package	Weight	Shipping
SDURB1060CT	D <sup>2</sup> PAK	1.85g	800pcs / reel
SDURB1060CTTR	D <sup>2</sup> PAK	1.85g	800pcs / reel
SDURD1060CT	DPAK	0.39g	2500pcs / reel
SDURD1060CTTR	DPAK	0.39g	2500pcs / reel

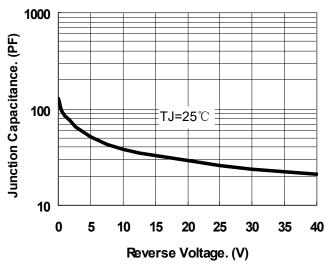
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.







# **Ratings and Characteristics Curves**



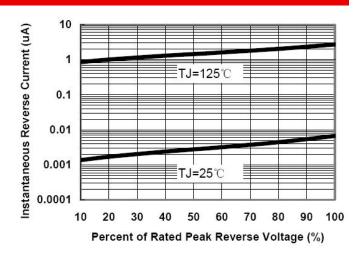


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

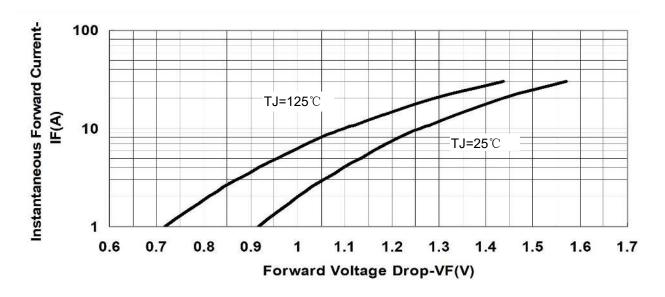


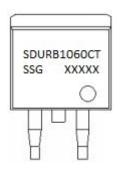
Fig.3-Typical Forward Voltage Drop Characteristics







## **Marking Diagram**





#### Where XXXXX is YYWWL

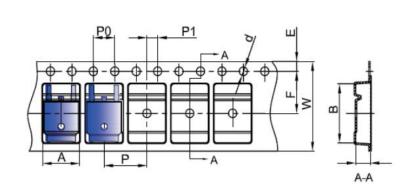
SDUR = Device Type
B/D = Package type
10 = Forward Current (10A)
60 = Reverse Voltage (600V)
CT = Configuration

CT = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

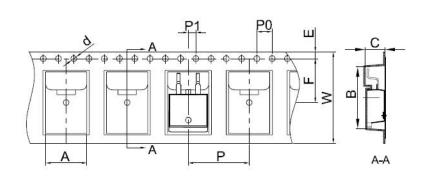
Epoxy resin UL:94V-0

### **Carrier Tape & Reel Specification DPAK**



SYMBOL	Millimeters			
STWBOL	Min.	Max.		
Α	6.80	7.00		
В	10.40	10.60		
С	2.60	2.80		
d	Ф1.45	Ф1.65		
E	1.65	1.85		
F	7.40	7.60		
P0	3.90	4.10		
Р	7.90	8.10		
P1	1.90	2.10		
W	15.90	16.30		

## Carrier Tape & Reel Specification D<sup>2</sup>PAK



SYMBOL	Millimeters			
STWIDOL	Min.	Max.		
Α	10.70	10.90		
В	16.03	16.23		
С	5.11	5.31		
d	1.45	1.65		
E	1.65	1.85		
F	11.40	11.60		
P0	3.90	4.10		
Р	15.90	16.10		
P1	1.90	2.10		
W	23.90	24.30		

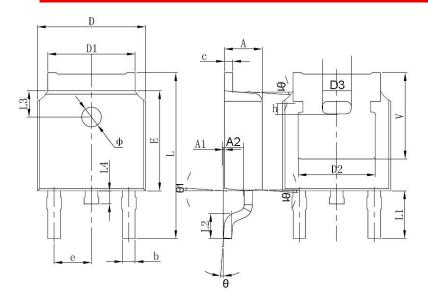
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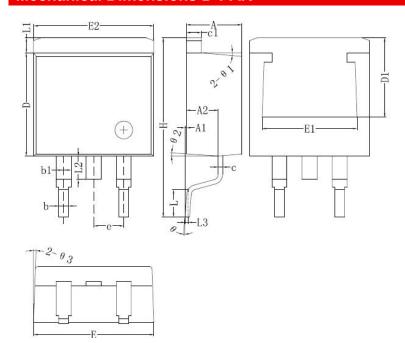


#### **Mechanical Dimensions DPAK**



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
Α	2.20	2.40	0.087	0.094
A1	0.00	0.127	0.000	0.005
b	0.66	0.86	0.026	0.034
С	0.46	0.60	0.018	0.024
D	6.50	6.70	0.256	0.264
D1	5.13	5.46	0.202	0.215
D2	4.83	REF.	0.190 REF.	
E	6.00	6.20	0.236	0.244
е	2.186	2.386	0.086	0.094
L	9.70	10.40	0.381	0.409
L1	2.90	REF.	0.144 REF.	
L2	1.40	1.70	0.055	0.067
L3	1.60 REF.		0.063 REF.	
L4	0.60	1.00	0.024	0.039
Ф	1.10	1.30	0.043	0.051
Θ	0°	8°	0°	8°
h	0.00	0.30	0.000	0.012
V	5.35 REF.		0.211 REF.	

### **Mechanical Dimensions D<sup>2</sup>PAK**



	Dimensions in millimeters				
Symbol	Min.	Typical	Max.		
Α	4.47	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.50	8.70	8.90		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.31		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.74		
L1	1.12	1.27	1.42		
L2	1.30		2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

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